# IS24C32A/B IS24C64A/B

# ISSI<sup>®</sup>

# 64K-bit/32K-bit 2-WIRE SERIAL CMOS EEPROM

APRIL 2006

## FEATURES

- Two-Wire Serial Interface, I<sup>2</sup>C<sup>™</sup> Compatible —Bi-directional data transfer protocol
- Wide Voltage Operation
   -Vcc = 1.8V to 5.5V
- 400 KHz (2.5V) and 1MHz (5.0V) Compatible
- Low Power CMOS Technology
  - -Standby Current less than 6 µA (5.0V)
  - -Read Current less than 2 mA (5.0V)
  - -Write Current less than 3 mA (5.0V)
- Hardware Data Protection
  - –IS24C32A/64A: WP protects entire array
    –IS24C32B/64B: WP protects top quarter of array
- Sequential Read Feature
- Filtered Inputs for Noise Suppression
- Self time write cycle with auto clear 5 ms max.@ 2.5V
- Organization:
  - -IS24C32A/B: 4Kx8 (128 pages of 32 bytes) -IS24C64A/B: 8Kx8 (256 pages of 32 bytes)
- 32 Byte Page Write Buffer
- High Reliability
  - -Endurance: 1,000,000 Cycles
  - -Data Retention: 100 Years
- Automotive and Industrial temperature ranges
- 8-pin PDIP, 8-pin SOIC, 8-pin TSSOP, and 8-pin MSOP packages
- Lead-free Available

# DESCRIPTION

The IS24C32A/B and IS24C64A/B are electrically erasable PROM devices that use the standard 2-wire interface for communications. The IS24C32A/B and IS24C64A/B contain a memory array of 32K-bits (4K x 8) and 64K-bits (8K x 8), respectively. Each device is organized into 32 byte pages for page write mode.

This EEPROM operates in a wide voltage range of 1.8V to 5.5V to be compatible with most application voltages. ISSI designed this device family to be a practical, low-power 2-wire EEPROM solution. The devices are available in 8-pin PDIP, 8-pin SOIC, 8-pin TSSOP, and 8-pin MSOP packages.

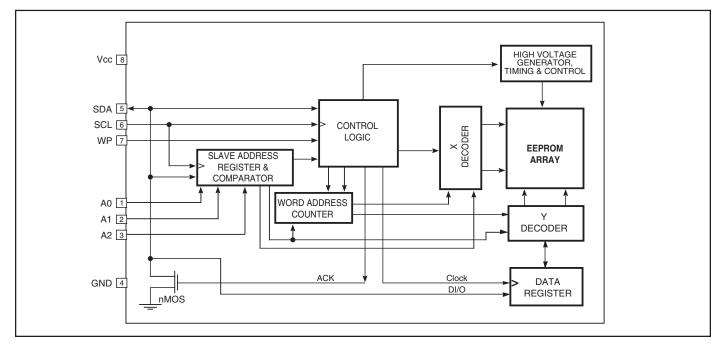
The IS24C32A/32B/64A/64B (IS24CXX) maintains compatibility with the popular 2-wire bus protocol, so it is easy to use in applications implementing this bus type. The simple bus consists of the Serial Clock wire (SCL) and the Serial Data wire (SDA). Using the bus, a Master device such as a microcontroller is usually connected to one or more Slave devices such as this device. The bit stream over the SDA line includes a series of bytes, which identifies a particular Slave device, an instruction, an address within that Slave device, and a series of data, if appropriate. The IS24CXX has a Write Protect pin (WP) to allow blocking of any write instruction transmitted over the bus.

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#### FUNCTIONAL BLOCK DIAGRAM



#### **PIN DESCRIPTIONS**

A0-A2	Address Inputs
SDA	Serial Address/Data I/O
SCL	Serial Clock Input
WP	Write Protect Input
Vcc	Power Supply
GND	Ground

#### SCL

This input clock pin is used to synchronize the data transfer to and from the device.

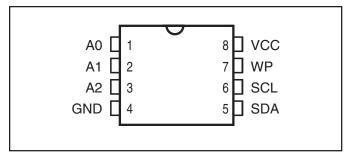
#### SDA

The SDA is a Bi-directional pin used to transfer addresses and data into and out of the device. The SDA pin is an open drain output and can be wire-Ored with other open drain or open collector outputs. The SDA bus *requires* a pullup resistor to Vcc.

#### A0, A1, A2

The A0, A1 and A2 are the device address inputs that are hardwired or left not connected for hardware compatibility with the 24C16. When pins are hardwired, as many as eight 32K/64K devices may be addressed on a single bus system. When the pins are not hardwired, the default values of A0, A1, and A2 are zero.

#### PIN CONFIGURATION 8-Pin DIP, SOIC, TSSOP, and MSOP



#### WP

WP is the Write Protect pin. The input level determines if all, partial, or none of the array is protected from modifications.

#### Write Protection

Array Addresses Protected				
WP	IS24C32A/64A	IS24C32B	IS24C64B	
GND or floating	None	None	None	
Vcc	Entire Array	C00h -FFFh	1800h -1FFFh	

#### **DEVICE OPERATION**

IS24CXX features serial communication and supports a bidirectional 2-wire bus transmission protocol called  $I^2C^{TM}$ .

#### 2-WIRE BUS

The two-wire bus is defined as a Serial Data line (SDA), and a Serial Clock line (SCL). The protocol defines any device that sends data onto the SDA bus as a transmitter, and the receiving devices as receivers. The bus is controlled by a Master device that generates the SCL, controls the bus access, and generates the Stop and Start conditions. The IS24CXX is the Slave device on the bus.

#### The Bus Protocol:

- Data transfer may be initiated only when the bus is not busy
- During a data transfer, the SDA line must remain stable whenever the SCL line is high. Any changes in the SDA line while the SCL line is high will be interpreted as a Start or Stop condition.

The state of the SDA line represents valid data after a Start condition. The SDA line must be stable for the duration of the High period of the clock signal. The data on the SDA line may be changed during the Low period of the clock signal. There is one clock pulse per bit of data. Each data transfer is initiated with a Start condition and terminated with a Stop condition.

#### **Start Condition**

The Start condition precedes all commands to the device and is defined as a High to Low transition of SDA when SCL is High. The EEPROM monitors the SDA and SCL lines and will not respond until the Start condition is met.

#### **Stop Condition**

The Stop condition is defined as a Low to High transition of SDA when SCL is High. All operations must end with a Stop condition.

#### Acknowledge (ACK)

After a successful data transfer, each receiving device is required to generate an ACK. The Acknowledging device pulls down the SDA line.

#### Reset

The IS24CXX contains a reset function in case the 2wire bus transmission is accidentally interrupted (eg. a power loss), or needs to be terminated mid-stream. The reset is caused when the Master device creates a Start condition. To do this, it may be necessary for the Master device to monitor the SDA line while cycling the SCL up to nine times. (For each clock signal transition to High, the Master checks for a High level on SDA.)

#### **Standby Mode**

Power consumption is reduced in standby mode. The IS24CXX will enter standby mode: a) At Power-up, and remain in it until SCL or SDA toggles; b) Following the Stop signal if a no write operation is initiated; or c) Following any internal write operation.

#### **DEVICE ADDRESSING**

The Master begins a transmission by sending a Start condition. The Master then sends the address of the particular Slave devices it is requesting. The Slave device (Fig. 5) address is 8 bits.

The four most significant bits of the Slave address are fixed as 1010 for the IS24CXX.

The next three bits of the Slave address are A0, A1, and A2, and are used in comparison with the hard-wired input values on the A0, A1, and A2 pins. Up to eight IS24CXX units may share the 2-wire bus.

The last bit of the Slave address specifies whether a Read or Write operation is to be performed. When this bit is set to 1, a Read operation is selected, and when set to 0, a Write operation is selected.

After the Master transmits the Start condition and Slave address byte (Fig. 5), the appropriate 2-wire Slave (eg.IS24C64A) will respond with ACK on the SDA line. The Slave will pull down the SDA on the ninth clock cycle, signaling that it received the eight bits of data. The selected EEPROM then prepares for a Read or Write operation by monitoring the bus.

#### WRITE OPERATION

#### **Byte Write**

In the Byte Write mode, the Master device sends the Start condition and the Slave address information (with the R/W set to Zero) to the Slave device. After the Slave generates an ACK, the Master sends the two byte address that is to be written into the address pointer of the IS24CXX. After receiving another ACK from the Slave, the Master device transmits the data byte to be written into the address memory location. The IS24CXX acknowledges once more and the Master generates the Stop condition, at which time the device begins its internal programming cycle. While this internal cycle is in progress, the device will not respond to any request from the Master device.

#### **Page Write**

The IS24CXX is capable of 32-byte Page-Write operation. A Page-Write is initiated in the same manner as a Byte Write, but instead of terminating the internal Write cycle after the first data word is transferred, the Master device can transmit up to 31 more bytes. After the receipt of each data word, the EEPROM responds immediately with an ACK on SDA line, and the five lower order data word address bits are internally incremented by one, while the higher order bits of the data word address remain constant. If a byte address is incremented from the last byte of a page, it returns to the first byte of that page. If the Master device should transmit more than 32 bytes prior to issuing the Stop condition, the address counter will "roll over," and the previously written data will be overwritten. Once all 32 bytes are received and the Stop condition has been sent by the Master, the internal programming cycle begins. At this point, all received data is written to the IS24CXX in a single Write cycle. All inputs are disabled until completion of the internal Write cycle.

#### Acknowledge (ACK) Polling

The disabling of the inputs can be used to take advantage of the typical Write cycle time. Once the Stop condition is issued to indicate the end of the host's Write operation, the IS24CXX initiates the internal Write cycle. ACK polling can be initiated immediately. This involves issuing the Start condition followed by the Slave address for a Write operation. If the EEPROM is still busy with the Write operation, no ACK will be returned. If the IS24CXX has completed the Write operation, an ACK will be returned and the host can then proceed with the next Read or Write operation.

#### **READ OPERATION**

Read operations are initiated in the same manner as Write operations, except that the  $(R/\overline{W})$  bit of the Slave address is set to "1". There are three Read operation options: current address read, random address read and sequential read.

#### **Current Address Read**

The IS24CXX contains an internal address counter which maintains the address of the last byte accessed, incremented by one. For example, if the previous operation is either a Read or Write operation addressed to the address location n, the internal address counter would increment to address location n+1. When the EEPROM receives the Slave Addressing Byte with a Read operation (R/W bit set to "1"), it will respond an ACK and transmit the 8-bit data byte stored at address location n+1. The Master should not acknowledge the transfer but should generate a Stop condition so the IS24CXX discontinues transmission. If 'n' is the last byte of the memory, the data from location '0' will be transmitted. (Refer to Figure 8. Current Address Read Diagram.)

#### Random Address Read

Selective Read operations allow the Master device to select at random any memory location for a Read operation. The Master device first performs a 'dummy' Write operation by sending the Start condition, Slave address and byte address of the location it wishes to read. After the IS24CXX acknowledges the byte address, the Master device resends the Start condition and the Slave address, this time with the  $R/\overline{W}$  bit set to one. The EEPROM then responds with its ACK and sends the data requested. The Master device does not send an ACK but will generate a Stop condition. (Refer to Figure 9. Random Address Read Diagram.)

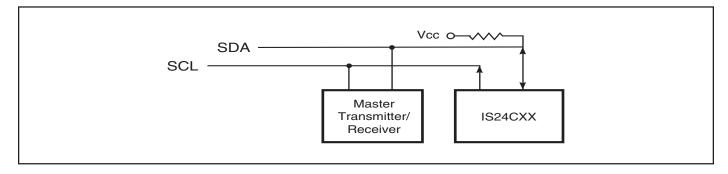
#### **Sequential Read**

Sequential Reads can be initiated as either a Current Address Read or Random Address Read. After the IS24CXX sends the initial byte sequence, the Master device now responds with an ACK indicating it requires additional data from the IS24CXX. The EEPROM continues to output data for each ACK received. The Master device terminates the sequential Read operation by pulling SDA High (no ACK) indicating the last data word to be read, followed by a Stop condition.

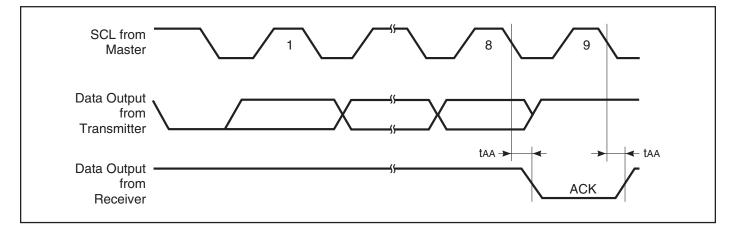
The data output is sequential, with the data from address n followed by the data from address n+1, n+2 ... etc. The address counter increments by one automatically, allowing the entire memory contents to be serially read during sequential Read operation. When the memory address boundary of 8191 for IS24C64A/B or 4095 for IS24C32A/B (depending on the device) is reached, the address counter "rolls over" to address 0, and the device continues to output data. (Refer to Figure 10. Sequential Read Diagram).



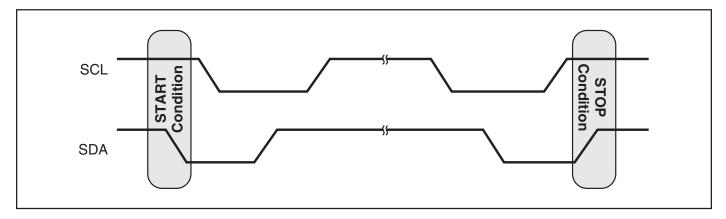
#### Figure 1. Typical System Bus Configuration



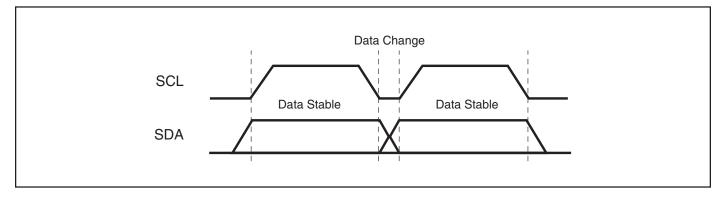
#### Figure 2. Output Acknowledge



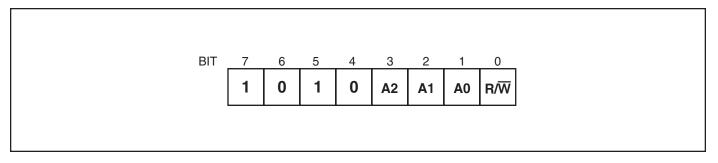
#### Figure 3. START and STOP Conditions



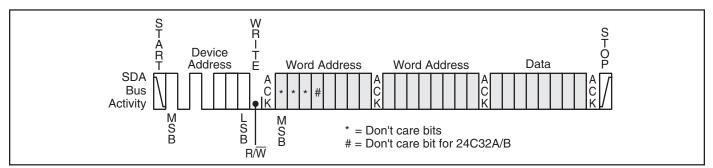
#### Figure 4. Data Validity Protocol



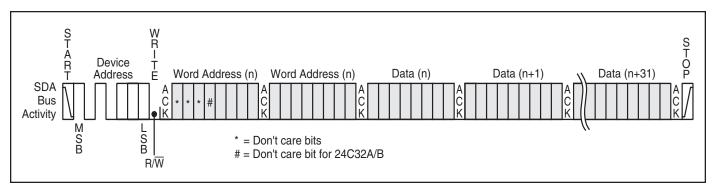
#### Figure 5. Slave Address



#### Figure 6. Byte Write



## Figure 7. Page Write



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#### Figure 8. Current Address Read

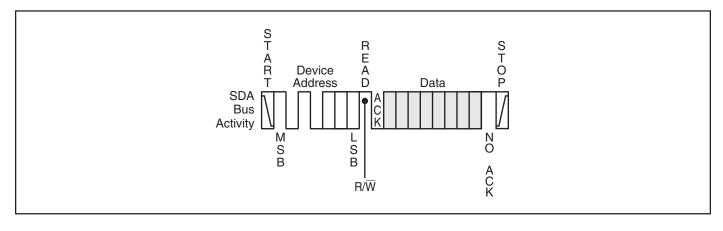


Figure 9. Random Address Read

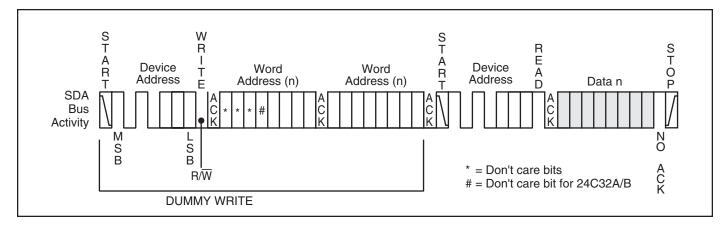
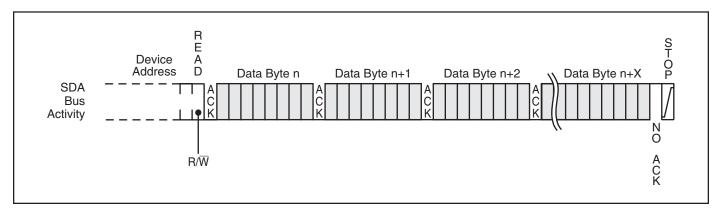


Figure 10. Sequential Read



#### **ABSOLUTE MAXIMUM RATINGS(1)**

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	-0.5 to +6.5	V
VP	Voltage on Any Pin	-0.5 to Vcc + 0.5	V
TBIAS	Temperature Under Bias	-55 to +125	°C
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	Output Current	5	mA

Notes:

1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### OPERATING RANGE (IS24C64A/B-2 and IS24C32A/B-2)

Range	Ambient Temperature	Vcc	
Industrial	–40°C to +85°C	1.8V to 5.5V	

Note: ISSI offers Industrial grade for Commerical applications (0°C to +70°C).

#### OPERATING RANGE (IS24C64A/B-3 and IS24C32A/B-3)

Range	Ambient Temperature	Vcc	
Automotive	–40°C to +125°C	2.5V to 5.5V	

#### CAPACITANCE<sup>(1,2)</sup>

Symbol	Parameter	Conditions	Max.	Unit
CIN	Input Capacitance	VIN = 0V	6	pF
Соит	Output Capacitance	Vout = 0V	8	pF

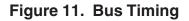
#### Notes:

1. Tested initially and after any design or process changes that may affect these parameters.

2. Test conditions:  $T_A = 25^{\circ}C$ , f = 1 MHz, Vcc = 5.0V.



#### **AC WAVEFORMS**



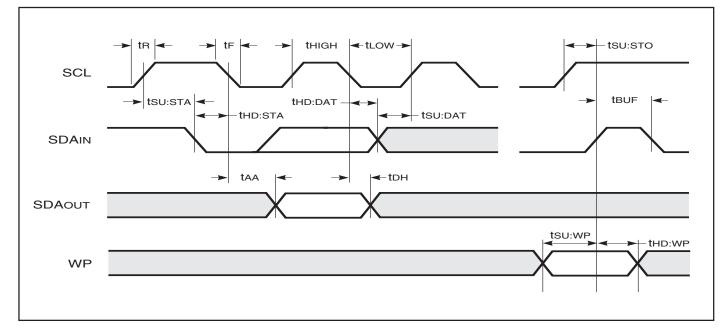
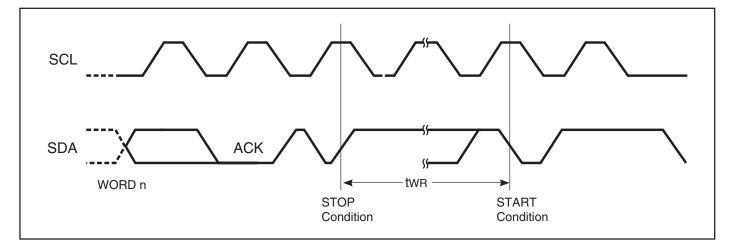


Figure 12. Write Cycle Timing



#### DC ELECTRICAL CHARACTERISTICS Industrial (TA = -40°C to +85°C), Automotive (TA = -40°C to +125°C)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
VoL1	Output Low Voltage	Vcc = 1.8V, $IoL = 0.15 mA$	—	0.2	V
Vol2	Output Low Voltage	Vcc = 2.5V, $IoL = 3 mA$	—	0.4	V
Vih	Input High Voltage		Vcc x 0.7	Vcc + 0.5	V
VIL	Input Low Voltage		-1.0	Vcc x 0.3	V
L	Input Leakage Current	VIN = Vcc max.	_	3	μA
Ilo	Output Leakage Current		—	3	μA

Notes: VIL min and VIH max are reference only and are not tested.

#### **POWER SUPPLY CHARACTERISTICS** Industrial (T<sub>A</sub> = -40°C to +85°C), Automotive (T<sub>A</sub> = -40°C to +125°C)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
lcc1	Vcc Operating Current	Read at 400 KHz (Vcc = 5V)	—	2.0	mA
lcc2	Vcc Operating Current	Write at 400 KHz (Vcc = 5V)	—	3.0	mA
IsB1	Standby Current	Vcc = 1.8V	_	1	μA
Isb2	Standby Current	Vcc = 2.5V		2	μA
Isb3	Standby Current	Vcc = 5.0V	_	6	μA

#### **AC ELECTRICAL CHARACTERISTICS** Industrial (TA = -40°C to +85°C)

		1.8V ≤ V	cc < 2.5V	2.5V ≤ Vo	cc < 4.5V	4.5V ≤ Vo	c ≤ 5.5	<b>V</b> <sup>(1)</sup>
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
fscl	SCL Clock Frequency	0	100	0	400	0	1000	KHz
Т	Noise Suppression Time <sup>(1)</sup>	_	100	_	50	_	50	ns
<b>t</b> Low	Clock Low Period	4.7	_	1.2	_	0.6	_	μs
<b>t</b> High	Clock High Period	4	_	0.6	_	0.4	_	μs
<b>t</b> BUF	Bus Free Time Before New Transmission <sup>(1)</sup>	4.7	_	1.2	_	0.5	_	μs
tsu:sta	Start Condition Setup Time	4	_	0.6	_	0.25	_	μs
tsu:sto	Stop Condition Setup Time	4	_	0.6	_	0.25	_	μs
thd:sta	Start Condition Hold Time	4	_	0.6	_	0.25	_	μs
thd:sto	Stop Condition Hold Time	4	_	0.6	_	0.25	_	μs
tsu:dat	Data In Setup Time	100	_	100	_	100	_	ns
thd:dat	Data In Hold Time	0	_	0	_	0	_	ns
tsu:wp	WP pin Setup Time	4	_	0.6	_	0.6	_	μs
thd:wp	WP pin Hold Time	4.7	_	1.2	_	1.2	_	μs
tон	Data Out Hold Time (SCL Low to SDA Data Out Change)	100	—	50	_	50	—	ns
taa	Clock to Output (SCL Low to SDA Data Out Valid)	100	3500	50	900	50	400	ns
tR	SCL and SDA Rise Time <sup>(1)</sup>	_	1000	_	300	_	300	ns
tF	SCL and SDA Fall Time <sup>(1)</sup>	_	300	_	300	_	100	ns
twn	Write Cycle Time		5	_	5	_	5	ms

Note: 1. These parameters are characterized but not 100% tested.

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#### **AC ELECTRICAL CHARACTERISTICS** Automotive (TA = -40°C to +125°C)

			c < 4.5V	4.5V ≤ Vo	c ≤ 5.5V <sup>(1)</sup>	)
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
fscl	SCL Clock Frequency	0	400	0	1000	KHz
Т	Noise Suppression Time <sup>(1)</sup>	—	50	_	50	ns
tLow	Clock Low Period	1.2	—	0.6	—	μs
<b>t</b> High	Clock High Period	0.6	—	0.4	—	μs
tbuf	Bus Free Time Before New Transmission <sup>(1)</sup>	1.2	—	0.5	—	μs
tsu:sta	Start Condition Setup Time	0.6	—	0.25	—	μs
tsu:sto	Stop Condition Setup Time	0.6	_	0.25	_	μs
thd:sta	Start Condition Hold Time	0.6	_	0.25	_	μs
thd:sto	Stop Condition Hold Time	0.6	_	0.25	_	μs
tsu:dat	Data In Setup Time	100	_	100	_	ns
thd:dat	Data In Hold Time	0	_	0	_	ns
tsu:wp	WP pin Setup Time	0.6	_	0.6	_	μs
thd:wp	WP pin Hold Time	1.2	_	1.2		μs
tdн	Data Out Hold Time (SCL Low to SDA Data Out Change	) 50	_	50		ns
taa	Clock to Output (SCL Low to SDA Data Out Valid)	50	900	50	550	ns
tR	SCL and SDA Rise Time <sup>(1)</sup>	_	300		300	ns
t⊨	SCL and SDA Fall Time <sup>(1)</sup>	_	300		100	ns
twr	Write Cycle Time	_	10		5	ms

Note:

1. These parameters are characterized but not 100% tested.

#### **ORDERING INFORMATION**

#### Industrial Range: -40°C to +85°C, Lead-free

Voltage Range	PartNumber	Package
1.8V to 5.5V	IS24C32A-2PLI IS24C32A-2GLI IS24C32A-2ZLI IS24C32A-2ZLI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP MSOP
1.8V to 5.5V	IS24C32B-2PLI IS24C32B-2GLI IS24C32B-2ZLI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP
1.8V to 5.5V	IS24C64A-2PLI IS24C64A-2GLI IS24C64A-2ZLI IS24C64A-2SLI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP MSOP
1.8V to 5.5V	IS24C64B-2PLI IS24C64B-2GLI IS24C64B-2ZLI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP

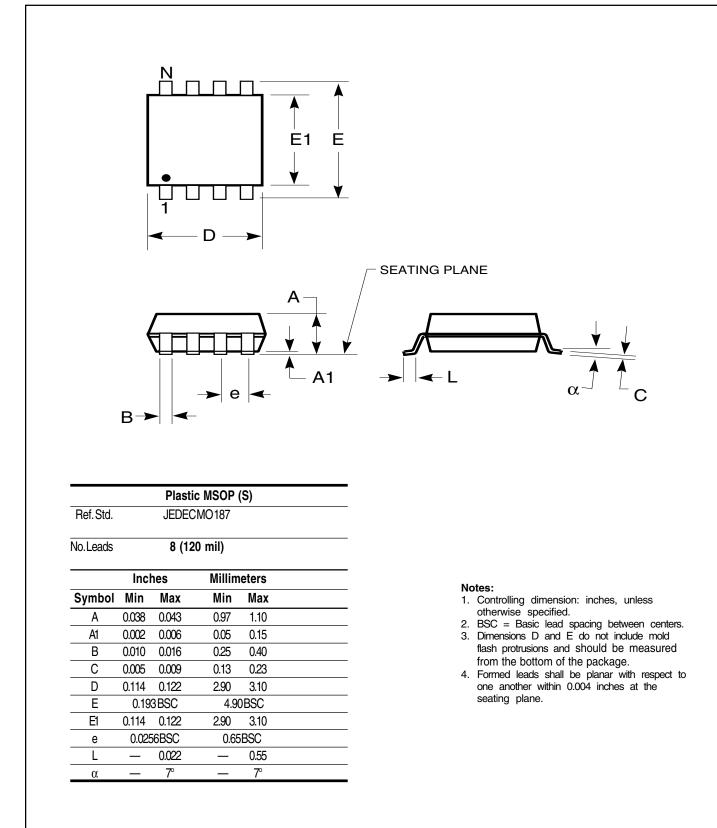
## ORDERING INFORMATION Industrial Range: -40°C to +85°C

Voltage Range	PartNumber	Package	
1.8V to 5.5V	IS24C32A-2PI IS24C32A-2GI IS24C32A-2ZI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP	
1.8V to 5.5V	IS24C32B-2PI IS24C32B-2GI IS24C32B-2ZI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP	
1.8V to 5.5V	IS24C64A-2PI IS24C64A-2GI IS24C64A-2ZI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP	
1.8V to 5.5V	IS24C64B-2PI IS24C64B-2GI IS24C64B-2ZI	300-mil Plastic DIP Small Outline (JEDEC STD) TSSOP	



## Plastic MSOP

Package Code: S



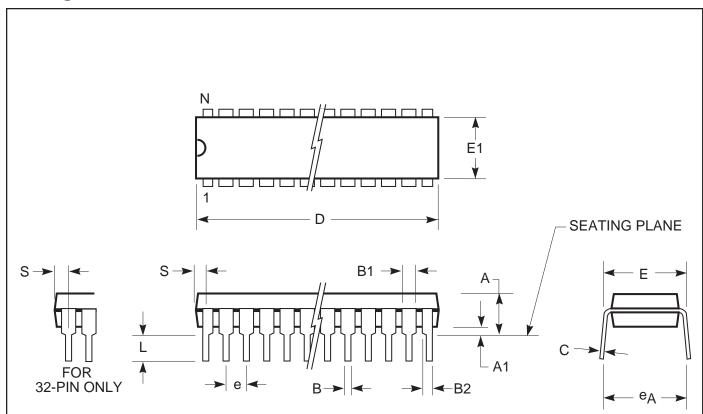
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# **PACKAGING INFORMATION**



# 300-mil Plastic DIP Package Code: N,P



	MILLIMETERS		INCHES	
Sym.	Min.	Max.	Min.	Max.
N0. Leads		8		
A	3.68	4.57	0.145	0.180
A1	0.38	_	0.015	
В	0.36	0.56	0.014	0.022
B1	1.14	1.52	0.045	0.060
B2	0.81	1.17	0.032	0.046
С	0.20	0.33	0.008	0.013
D	9.12	9.53	0.359	0.375
E	7.62	8.26	0.300	0.325
E1	6.20	6.60	0.244	0.260
ед	8.13	9.65	0.320	0.380
e	2.54 BSC		0.100 BSC	
L	3.18	_	0.125	
S	0.64	0.762	0.025	0.030

#### Notes:

- 1. Controlling dimension: inches, unless otherwise specified.
- 2. BSC = Basic lead spacing between centers.
- Dimensions D and E1 do not include mold flash protrusions and should be measured from the bottom of the package.
- 4. Formed leads shall be planar with respect to one another within 0.004 inches at the seating plane.

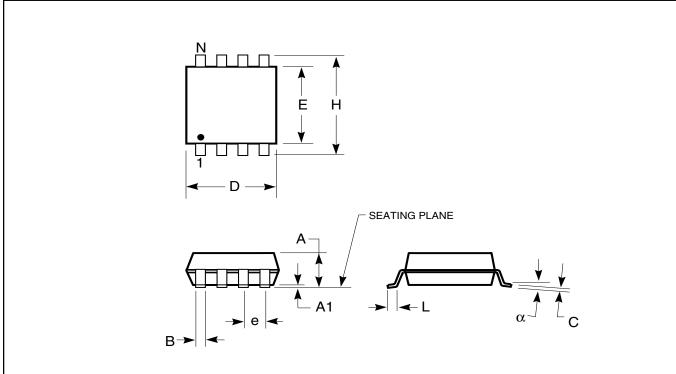
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# PACKAGING INFORMATION



#### 150-mil Plastic SOP Package Code: G, GR



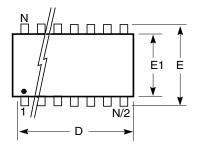
	150	)-mil Plastic §	SOP (G, GR)	
Symbol	Min	Max	Min	Max
Ref. Std.	Inches		mm	
No. Leads	8		8	
Α	_	0.068	_	1.73
A1	0.004	0.009	0.1	0.23
В	0.013	0.020	0.33	0.51
С	0.007	0.010	0.18	0.25
D	0.189	0.197	4.8	5
E	0.150	0.157	3.81	3.99
Н	0.228	0.245	5.79	6.22
е	0.050 BSC		1.27 BSC	
L	0.020	0.035	0.51	0.89

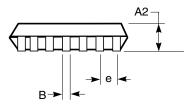
#### Notes:

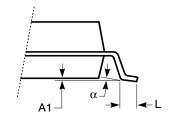
- 1. Controlling dimension: inches, unless otherwise specified.
- 2. BSC = Basic lead spacing between centers.
- 3. Dimensions D and E1 do not include mold flash protrusions and should be measured from the bottom of the package.
- 4. Formed leads shall be planar with respect to one another within 0.004 inches at the seating plane.

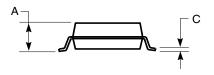
# **PACKAGING INFORMATION**

#### Thin Shrink Small Outline TSSOP Package Code: Z (8 pin, 14 pin)









		TSSOP	' (Z)	
Ref. Std. JEDEC MO-153				
No. Leads 8				
	Millim	eters	Inches	
Symbol	Min	Max	Min	Max
А	_	1.20	_	0.047
A1	0.05	0.15	0.002	0.006
A2	0.80	1.05	0.032	0.041
В	0.19	0.30	0.007	0.012
С	0.09	0.20	0.004	0.008
D	2.90	3.10	0.114	0.122
E1	4.30	4.50	0.169	0.177
Е	6.40	) BSC	0.25	2 BSC
е	0.65	5 BSC	0.02	6 BSC
L	0.45	0.75	0.018	0.030
α	_	8°	_	8°

TSSOP (Z)						
Ref. Std. JEDEC MO-153						
No. Leads 14						
	Millim	eters	Inches			
Symbol	Min	Max	Min	Max		
A	_	1.20	_	0.047		
A1	0.05	0.15	0.002	0.006		
A2	0.80	1.05	0.031	0.041		
В	0.19	0.30	0.007	0.012		
С	0.09	0.20	0.0035	0.008		
D	4.90	5.10	0.193	0.201		
E1	4.30	4.50	0.170	0.177		
E	6.40 BSC		0.252 BSC			
е	0.65 BSC		0.02	6 BSC		
L	0.45	0.75	0.0177	0.0295		
α	—	8°	_	8°		

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